ELEC-313 Lab 7: MOSFET Amplifier Circuits

November 12, 2013

Date Performed: November 06, 2013 Partners: Charles Pittman

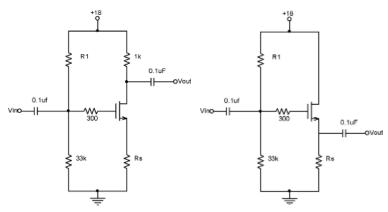
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1 Objective

2 Equipment

Transistor: 2N7000 Power supply: HP E3631A Function generator: HP 33120 Multimeter: HP 34401A Oscilloscope: Agilent 54622D Capacitors: $0.1\,\mu\text{F}$ Resistors: $100\,\Omega$, $300\,\Omega$, $470\,\Omega$, $1\,\mathrm{k}\Omega$ (x2) $33\,\mathrm{k}\Omega$, $100\,\mathrm{k}\Omega$ (x2)

3 Schematics



- (a) Common-source amplifier
- (b) Source-follower amplifier

Figure 1: Circuits used in this lab. $R_1 = 100 \,\mathrm{k}\Omega,\, R_s = 470 \,\Omega$

4 Procedure

The following procedures were identified to observe the basic operation of MOS-FET amplifier circuits.

4.1 Common-Source Amplifier

- 1. Build the circuit of figure 1. Use the closest resistor values available for R1 and Rs.
- 2. Measure and record the dc voltages at all terminals of the MOSFET. Compute the drain current.
- 3. Set the function generator for a 200mV PP , 20-kHz sine wave with 0V DC offset. Connect it to V IN .

- 4. Connect a 100kohm load resistor from V OUT to ground. This will be considered a no-load scenario.
- 5. Connect CHANNEL 1 of the oscilloscope to V IN and CHANNEL 2 to V OUT . Set the scope to trigger off of CHANNEL 1 . This setting is accessed using the EDGE button on the oscilloscope.
- 6. Adjust the function generator to an amplitude of 200mV pp as measured on CHANNEL 1 of the oscilloscope.
- 7. Measure the peak-to-peak output voltage on CHANNEL 2 of the oscilloscope.
- 8. Repeat step 6 for input voltages (as measured on CHANNEL 1 of the oscilloscope) of 300, 400, 500, 600, 700, 800, 900, and 1000 mV pp .
- 9. Replace the 100kohm from V OUT to ground with a 1kohm load resistor.
- 10. Reset the function generator to an amplitude of 200mV pp as measured on CHANNEL 1 of the oscilloscope.
- 11. Measure the peak-to-peak output voltage on CHANNEL 2 of the oscilloscope.

4.2 Source-Follower Amplifier

- 1. Construct the circuit of figure 2 by removing the 1kohm drain resistor and moving the output capacitor to the source of the MOSFET.
- 2. Measure and record the dc voltages at all terminals of the MOSFET. Compute the drain current.
- 3. Connect a 100kohm load resistor from V OUT to ground. This will be considered a no-load scenario.
- 4. Adjust the function generator to an amplitude of 200mV pp as measured on CHANNEL 1 of the oscilloscope.5) Measure the peak-to-peak output voltage on CHANNEL 2 of the oscilloscope.
- 5. Repeat step 4 for input voltages (as measured on CHANNEL 1 of the oscilloscope) of $300,\,400,\,500,\,600,\,700,\,800,\,900,\,$ and $1000 \mathrm{mV}$ pp .
- 6. Reset the function generator to an amplitude of 200mV pp as measured on CHANNEL 1 of the oscilloscope.
- Replace the 100kohm resistor from V OUT to ground with a 1kohm resistor and measure the peak-to-peak output voltage on CHANNEL 2 of the oscilloscope.
- 8. Now replace the 1kohm load resistor with a 100ohm load resistor and measure the peak-to-peak output voltage on CHANNEL 2 of the oscilloscope.

5 Results

5.1 Common-Source Amplifier

$$\begin{array}{c|ccccc} V_G & V_D & V_S & I_D \\ \hline 4.391 \, \mathrm{V} & 13.498 \, \mathrm{V} & 2.11 \, \mathrm{V} & 4.52 \, \mathrm{mA} \end{array}$$

Table 1: Transistor characteristics

$V_{in} (\mathrm{mV})$	V_{out} (V)
200	0.382
300	0.566
400	0.760
500	0.939
600	1.140
700	1.340
800	1.530
900	1.721
1000	1.90

Table 2: Common-source amplifier

5.2 Source-Follower Amplifier

$$\begin{array}{c|cccc} V_G & V_D & V_S & I_D \\ \hline 4.391 \, \mathrm{V} & 18.003 \, \mathrm{V} & 2.12 \, \mathrm{V} & 4.579 \, \mathrm{mA} \end{array}$$

Table 3: Transistor characteristics

6 Conclusion

7 Equations

$$V_{o,L} = V_{o,NL} \frac{R_L}{R_o + R_L} \tag{1}$$

$$V_G = \frac{V_{DD} \cdot 33 \,\mathrm{k}\Omega}{100 \,\mathrm{k}\Omega + 33 \,\mathrm{k}\Omega} \tag{2}$$

$$V_S = V_G \cdot \sqrt{\frac{I_D}{K_N}} - V_{TN} \tag{3}$$

$$V_D = V_{DD} - I_D \cdot 1 \,\mathrm{k}\Omega \tag{4}$$

$V_{in} (\mathrm{mV})$	$V_{out} (\mathrm{mV})$
200	182
300	268
400	360
500	451
600	541
700	634
800	725
900	813
1000	906

Table 4: Source-follower amplifier

	V_G (V)	V_D (V)	V_S (V)	$I_D \text{ (mA)}$
Measured	4.391	13.498	2.11	4.52
Theoretical	4.466	14.000	2.4214	4.00
% Difference	1.712%	3.719%	14.800%	11.500%

Table 5: % Difference

$$\%_{diff} = \frac{|measured - theoretical|}{theoretical} \times 100\%$$
 (5)